# NSN 5961-01-099-4159

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.170 inches and 0.210 inches

# **Terminal Length:**

0.500 inches

## **Overall Diameter:**

Between 0.209 inches and 0.230 inches

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-72

#### **Mounting Method:**

Terminal

#### Terminal Circle Diameter:

## 0.100 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

30.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage,

static, collector open

# **Current Rating Per Characteristic:**

50.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

300.0 milliwatts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

80063-sm-b-448902 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0